KRATTA, a versatile triple telescope array for charged reaction products

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Abstract

A new detection system KRATTA, Kraków Triple Telescope Array, is presented. This versatile, low resolution over a large dynamic range in particle type and energy is mandatory for studies of isotopic effects in heavy-ion reactions. Phenomena related to the isotopic composition of the reaction system and the emitted products have been shown to be useful for exploring the properties of neutron-rich nuclear matter as, e.g., encountered in neutron stars [1,2]. Their importance will increase with the availability of secondary beams of high intensity. Also studies of nuclear structure near the limits of stability improve the resolution of the first segment of the telescope. A comprehensive overview of the recent and future developments in this field of instrumentation can be found in Ref. [3].

Most of the existing charged particle detectors for the intermediate energy range (up to a few tens or hundreds of MeV/nucleon) base their identification on the two- or three-fold telescope method [4,5]. In order to provide the lowest possible identification threshold, the first layer of the telescope is usually made of a gas chamber (e.g. DELF [6], MULTICS [7], FASA [8], INDRA [9], ISIS [10], GARFIELD [11], FIASCO [12]) or of a thin Si detector (e.g. FAUST [13], LASSA [14], CHIMERA [15], HIRA [16], NIMROD [17], FAZIA [18]). The first, ΔE layer is then followed by one or two, thicker, Si detectors or scintillators. The option with the silicon ΔE layer has the advantage of a better resolution and is easier to handle, but usually results in higher thresholds and is costly. The presented KRATTA modules belong to this class of telescopes, however, they have been optimized to be budget friendly, without loosing the quality of detection. Instead of using the Si detectors of different thickness, they are using three identical, catalog size, photodiodes and two CsI(Tl) crystals. Thanks to the digital signal processing and the off-line pulse shape analysis, the obtained mass resolutions for light charged particles are very satisfactory in a broad energy range. On one hand, the pulse shape analysis allowed to reduce the energy threshold, resulting from the relatively thick first layer, by a factor of 3. On the other hand, it allowed to effectively double the thickness of the silicon ΔE layer, by combining the ionization components from the first two photodiodes, and consequently, to improve the resolution of the first segment of the telescope.

1. Introduction

Charged-particle detection and identification with isotopic resolution over a large dynamic range in particle type and energy is mandatory for studies of isotopic effects in heavy-ion reactions. Phenomena related to the isotopic composition of the reaction system and the emitted products have been shown to be useful for exploring the properties of neutron-rich nuclear matter as, e.g., encountered in neutron stars [1,2]. Their importance will increase with the availability of secondary beams of high intensity. Also studies of nuclear structure near the limits of stability require increasingly sophisticated and precise detection systems. A comprehensive overview of the recent and future developments in this field of instrumentation can be found in Ref. [3].

Most of the existing charged particle detectors for the intermediate energy range (up to a few tens or hundreds of MeV/nucleon) base their identification on the two- or three-fold telescope method [4,5]. In order to provide the lowest possible identification threshold, the first layer of the telescope is usually made of a gas chamber (e.g. DELF [6], MULTICS [7], FASA [8], INDRA [9], ISIS [10], GARFIELD [11], FIASCO [12]) or of a thin Si detector (e.g. FAUST [13], LASSA [14], CHIMERA [15], HIRA [16], NIMROD [17], FAZIA [18]). The first, ΔE layer is then followed by one or two, thicker, Si detectors or scintillators.

The option with the silicon ΔE layer has the advantage of a better resolution and is easier to handle, but usually results in higher thresholds and is costly. The presented KRATTA modules belong to this class of telescopes, however, they have been optimized to be budget friendly, without loosing the quality of detection. Instead of using the Si detectors of different thickness, they are using three identical, catalog size, photodiodes and two CsI(Tl) crystals. Thanks to the digital signal processing and the off-line pulse shape analysis, the obtained mass resolutions for light charged particles are very satisfactory in a broad energy range. On one hand, the pulse shape analysis allowed to reduce the energy threshold, resulting from the relatively thick first layer, by a factor of 3. On the other hand, it allowed to effectively double the thickness of the silicon ΔE layer, by combining the ionization components from the first two photodiodes, and consequently, to improve the resolution of the first segment of the telescope.

2. Motivation and requirements

The main parameters of the KRATTA array have been motivated by the needs of the ASY-EOS experiment [19]. This experiment has been designed to study the density dependence of the
nuclear symmetry energy by measuring flows and isotopic compositions of the reaction products from the $^{197}$Au+$^{197}$Au, $^{96}$Ru+$^{96}$Ru, and $^{96}$Zr+$^{96}$Zr reactions at 400 MeV/nucleon. During the experiment the most relevant products, neutrons and $Z=1$ and 2 particles, have been measured by the LAND [20] detector and the direction and magnitude of the impact vector were estimated using the CHIMERA [15] and ALADIN ToF-Wall [21] detectors. The KRATTA array has been designed to complement the neutron and hydrogen detection with LAND by measuring the isotopic composition and flow of light charged reaction products up to atomic number $Z \leq 7$, and specially, to identify the hydrogen and helium isotopes with a resolution much better than achievable with LAND. The array was placed on the opposite side of the beam with respect to LAND, and covered approximately the same solid angle (160 msr). It has been designed to detect energetic particles emerging from the “mid-rapidity” region of the 400 MeV/nucleon reactions. Modular design, portability, low thresholds (below 3 MeV/nucleon) and high maximum energy ($\sim$ 260 MeV/nucleon for p and $\alpha$) allow the array to be used in various configurations and experiments. In particular, it will very well suit the needs of the future cyclotron facility at IFJ-PAN in Kraków, planned for proton beams from 70 to 250 MeV. Last, but not least, the KRATTA modules are also compatible with the design of the existing Krakow Forward Wall Detector [22] and can be used for reaching complete coverage of the $2\pi$ azimuthal angle.

3. Active elements and geometry

The modules of KRATTA are composed of three large area HAMAMATSU PIN photodiodes for direct detection [23] and of two CsI(Tl) crystals [24]. The layout and dimensions of these active elements are presented in Fig. 1 and their main characteristics are summarized in Table 1.

The first photodiode (PD0 in Fig. 1) serves as a Si $\Delta E$ detector providing the ionization signal alone. It has been “reverse mount”, i.e. the ohmic side towards the incoming particles. The second photodiode (PD1), naturally “reverse mount”, works in a “Single Chip Telescope”, SCT [25], configuration and provides a composite signal combined of a direct (ionization) component and of a scintillation component coming from the thin crystal (CsI1). The third photodiode (PD2) reads out the light from the thick crystal (CsI2) and, in addition, provides an ionization signal for particles that punch through the crystal within its active area.

The larger front face of the longer crystal with respect to the rear face of the smaller one (see Fig. 1) permits its use at an about two times larger distance from the target, in configuration that completes the missing half of the FWD phoswich array [22]. The crystals have been polished and wrapped with a highly reflective ESR [26] foil, except for the front and back windows. The windows have been protected with 6 $\mu$m Mylar foils. The crystals were optically decoupled. The photodiode chips have been glued onto custom-made PCB frames and put in close optical contact with the crystal windows. The active elements have been placed inside aluminum boxes together with the charge preamplifiers (see Fig. 2). The photodiode frames and the aluminum housing reduced the geometric acceptance of a single module to about 54%. The active solid angle of a module amounts to 4.5 msr. The entrance window has been made of a 100 $\mu$m thick copper foil. During the experiment, 35 modules have

![Fig. 1. Schematic layout of the active elements.](image)

![Fig. 2. Single module content.](image)

<table>
<thead>
<tr>
<th>Table 1</th>
<th>Main characteristics of the active elements.</th>
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<tbody>
<tr>
<td><strong>Photodiodes [23]</strong></td>
<td></td>
</tr>
<tr>
<td>Active area</td>
<td>$28 \times 28$ mm$^2$</td>
</tr>
<tr>
<td>Thickness</td>
<td>$500 \pm 15$ $\mu$m</td>
</tr>
<tr>
<td>Thickness non-uniformity</td>
<td>$&lt; 3$ $\mu$m</td>
</tr>
<tr>
<td>Dead layers</td>
<td>1.5/20 $\mu$m front/rear</td>
</tr>
<tr>
<td>Surface orientation (FD)</td>
<td>(111)</td>
</tr>
<tr>
<td>Full depletion voltage</td>
<td>120–135 V</td>
</tr>
<tr>
<td>Dark current at FD</td>
<td>6–16 nA, typ. 9 nA</td>
</tr>
<tr>
<td>Terminal capacitance at FD</td>
<td>$190 \pm 3$ pF</td>
</tr>
<tr>
<td>Rise time (laser pulse)</td>
<td>40 ns</td>
</tr>
<tr>
<td>CsI(Tl) crystals [24]</td>
<td></td>
</tr>
<tr>
<td>Ti concentration</td>
<td>1500 ppm</td>
</tr>
<tr>
<td>Light output non-uniformity</td>
<td>$&lt; 7%$</td>
</tr>
<tr>
<td>Shape</td>
<td>Truncated pyramids</td>
</tr>
<tr>
<td>Tolerance</td>
<td>$\pm 0.1$ mm</td>
</tr>
<tr>
<td>Wrapping [26]</td>
<td></td>
</tr>
<tr>
<td>Reflectance</td>
<td>$&gt; 98%$</td>
</tr>
<tr>
<td>Thickness</td>
<td>65 $\mu$m</td>
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<table>
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<tr>
<th>Notes:</th>
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<tbody>
<tr>
<td>a Values from technical note.</td>
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<tr>
<td>b Values from manufacturer’s inspection sheet.</td>
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<tr>
<td>c Nominal values.</td>
</tr>
</tbody>
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They have been calculated using the ATIMA tables [27]. The main electronics and data acquisition functions are pre-designed, low noise, charge preamplifier [28]. The signal from each photodiode has been integrated with the own-channel, remote controlled, high voltage power supplies. The thresholds have been reverse biased at 120 V, using the in-house made 120-V preamplifiers. The preamplifier response has been modeled [29], by about 1.2 and 3.3 pf feedback capacitors, respectively. After optional amplification, the signals have been digitized with the 100 MHz, 14 bit digitizers [29] and stored for the off line analysis. All logical and digital electronics modules shown in Fig. 4 have been controlled with the RIO4 board [31] running LynxOS; MBS—Multi-Branch System, a GSI acquisition standard [32]; SMS—Shared Memory Segment.

4. Electronics and data acquisition

The main electronics and data acquisition functions are presented schematically in Fig. 4. The photodiodes (3 per module) have been reverse biased at 120 V, using the in-house made 120-channel, remote controlled, high voltage power supplies. The signal from each photodiode has been integrated with the own-design, low noise, charge preamplifier [28].

The preamps were supplied with ±6 V and their dynamic range spanned about 3.6 V. Three nominal charge gains of the preamplifiers have been used, depending on the azimuthal angle of the module: 44.5, 22.2 and 13.5 mV/MeV, with 1, 2 and 3.3 pf feedback capacitors, respectively. After optional amplification, the signals have been digitized with the 100 MHz, 14 bit digitizers [29] and stored for the off line analysis. All logical and digital electronics modules shown in Fig. 4 have been controlled with the RIO4 board [31] within a single VME crate. During the experiment, the 14 Flash ADC boards have been triggered with an external trigger split and delivered into each FADC module. The stored waveforms spanned 5.12 or 10.24 µs (512 or 1024 time bins), with a 2 µs pre-trigger enabling a precise baseline estimation. The shorter samples have been sufficient for the first photodiode supplying the fast ionization signal alone. The expected data throughput amounted to about 5 MB/s, assuming 1 kHz single hit rate. The actual data rate did not go beyond this estimate during the experiment. The digitizers have been remotely set up and monitored using a self-developed software. The data flow has been controlled using the standard GSI MBS system [32].

5. Pulse shape analysis

The pulse shape analysis has two main purposes in the case of KRATTA data. First of all, it has to enable the decomposition of the signals from the middle photodiode, PD1 (SCT), into the ionization and scintillation components. Second, it is used to resolve masses of particles stopped in the first photodiode, PD0, utilizing the relation between the range of a particle and the time characteristics of the induced current signal [33].

The following assumptions have been made to accomplish these two goals. The preamplifier response has been modeled using a simple parallel RC circuit approximation [34]:

\[
i(t) = \frac{dV(t)}{dt} + \frac{V(t)}{RC}
\]

where RC is the feedback coupling time constant, \(i(t)\) is the induced current due to the carrier motion in the photodiode, and \(V(t)\) is the measured voltage pulse. This relation assumes an
infinite open loop gain, small detector capacitance and a zero rise time of the charge integrator, which is an idealization, but enables an analytical approach. The induced current has been approximated with one direct (ionization), \( I_0(t) \), and two scintillation, \( I_{sk}(t) \), components, all of the same form:

\[
I_0(t) = Q_0 e^{-t/\tau_0} - e^{-t/\tau_0}
\]

\[
I_{sk}(t) = Q_{sk} e^{-t/\tau_{sk}} - e^{-t/\tau_{sk}} \quad k = 1,2
\]

where \( Q_0 \) are the induced charges and the \( \tau_{RD}, \tau_{RS} \) and the \( \tau_{FD}, \tau_{RD} \) are the rise and fall times for the respective component. The assumed shapes attempt to account for both, the complicated actual current pulse shape induced by the electrons and holes drifting in the photodiode [33], and for the instrumental rise time of the preamp. The assumed preampf response (1) and the current shapes (2) and (3), it was possible to obtain the corresponding analytical model shapes of the waveforms.

\[
V(t) = V_0 + V_0(t) + V_{sk}(t),
\]

\[
V_0(t) = RC \left( \frac{e^{-\Delta t/RC}}{(RC-\tau_{RD})(RC-\tau_{FD})} + \frac{e^{-\Delta t/\tau_{FD}}}{(\tau_{RD}-RC)(\tau_{FD}-RC)} \right)
\]

\[
V_{sk}(t) = RC \sum_{k=1}^{2} Q_{sk} \left( \frac{e^{-\Delta t/RC}}{(RC-\tau_{RS})(RC-\tau_{FD})} \right)
\]

\[
+ \left( \frac{e^{-\Delta t/\tau_{RS}}}{(\tau_{RD}-RC)(\tau_{FD}-\tau_{RS})} \right)
\]

\[
+ \left( \frac{e^{-\Delta t/\tau_{RD}}}{(\tau_{FD}-\tau_{RS})(\tau_{FD}-RC)} \right)
\]

where for generalization, \( V_0 \) is the baseline and \( \Delta t = t - t_0 \), with \( t_0 \) being the beginning of the pulse.

The two scintillation components (5) have been introduced to account for the fast and slow decay modes of the CsI(Tl) crystals. The rise times, \( \tau_{RD} \) and \( \tau_{RS} \), account for the photodiode, scintillator and the preamp rise times. Overall, the model depends on 11 parameters listed in Table 3.

The preamp fall time constant parameter \( RC \) has been determined individually for each chip by selecting the pulses with the fast ionization component alone. The resulting \( RC \) smaller than the nominal ones by a few \( \mu \)s due to small leakage currents. In order to describe precisely the shapes due to particles stopped in the first photodiode, PD0, both the time constants, \( \tau_{RD} \) and \( \tau_{RD} \), were fitted and the scintillation components were obviously not used. In case of PD1 and PD2, the rise and fall times \( \tau_{RD} \) and \( \tau_{FD} \) were fixed. The fits were done using the FUMILI [35] minimization package, a relatively fast and precise implementation of the Gauss–Newton algorithm. Constraining some of the parameters was found inevitable, not only to obtain a good description of the waveforms (\( \gamma^2 \)) but, at the same time, to maintain the global agreement between the reconstructed amplitudes of the three components and the predictions of the range-energy tables (see discussion of Figs. 16 and 17).

An additional advantage of using the digitization of the signals and the fitting method, was the knowledge of the actual charges \( Q \) for each component, irrespectively of the substantial ballistic deficit (reduction of the amplitude) due to a relatively short discharge time of the preamps (\( RC \sim 6 \mu s \)). For instance, the sum \( Q_{S1} + Q_{S2} \) represents the total light produced in the scintillators. For typical values of the parameters presented in Table 3, the ballistic deficit amounts to about 5–15% for the ionization signal and to about 25% and 50% for the fast and slow CsI(Tl) components, respectively. Usually, the fall time constant of the preamp is a compromise between the level of pile-ups, the baseline variation, and the ballistic deficit. However, since ballistic deficit is not an issue in our approach, the short preamp fall times, of the order of the time span of the waveform and of the slow CsI(Tl) decay time, have the additional advantage of making the maximum and the tail of the pulse visible within the digitized sample.

Waveforms of low energy particles stopped in the first photodiode, PD0, have been fitted with a single component of the form (4), with the time constant parameters treated as free fit parameters. A more precise time characteristics of the associated current pulse (2) was needed to perform a pulse shape based identification of these particles (see discussion of Fig. 13).

The quality of the fits is demonstrated in Fig. 5. The ordinate represents the measured voltage, in the FADC channels, which is about twice smaller than the actual one due to the matching of the 50 \( \Omega \) FADC input impedance. The hits corresponding to the selected waveforms are also marked in the identification maps presented in the next section.

Panel A of Fig. 5 shows a waveform for a low energy electron, particle or \( \gamma \), registered barely above the acquisition threshold and stopped in PD0 (see also Fig. 13). Here the measured histogram is visible and the deviations from the smooth fit visualize the level of the total noise. The resultant signal distortions, including the photodiode, preamplifier, FADC and pickup noise sources, have been observed on the level of 0.4 mV rms, corresponding to about 30 keV.

Panel B of Fig. 5 presents the quality of the fit with the shape given by an ionization component alone (4), applied to particles stopped in PD0. Its location in the identification map is presented in Fig. 13. This fit allowed for derivation of both, the rise and fall times and, therefore, also of the mode (position of maximum) of the associated current signal (2):

\[
\text{mode} = \frac{\tau_{RD} - \tau_{FD}}{\tau_{RD} - \tau_{FD}} \log \frac{\tau_{FD}}{\tau_{RD}}
\]

Panel C of Fig. 5 shows the waveform of a high energy \( \alpha \) particle stopped in the CsI2 crystal. The corresponding hit has been marked in Figs. 7 and 12.

Panels D–F of Fig. 5 show the evolution of the pulse shape of an \( \alpha \) particle detected and stopped in the SCT as its energy increases. The corresponding hits have been marked, when possible, in Figs. 6, 8–11.

The fitting of signals from PD2 (Fig. 5, panel C) produces small artificial ionization contributions for particles which actually do not hit the photodiode (see Fig. 7). It amounts, on average, to 1.7 \pm 0.5% of the total amplitude. Correspondingly, the artificial contribution of a scintillation component for particles stopped in the PD1 photodiode, and thus producing no light (see representative hit in panel D), is about 3.8 \pm 0.6%. These numbers specify the quality of the pulse shape parametrization and the systematic uncertainty of the decomposition into different components.
The artificial scintillation component has been removed by subtracting its well defined fraction from the total amplitude and thus making the ionization and scintillation components of the SCT almost perfectly orthogonal.

6. Performance

Figs. 6–13 present various identification (ID) maps obtained by using the parameters of the reconstructed waveform components. The strongest lines in Figs. 6–13 correspond to p, d, t, $^3$He, $\alpha$, and so on, from bottom to top, respectively (see Fig. 16 for precise labeling).

The reconstructed amplitude maps for the first two and the last two photodiodes of the KRATTA module are presented in Figs. 6 and 7.

The identification map in Fig. 6 shows a complex spectrum with each “ID-line” composed of two parts: an ordinary Si–Si hyperbolic segment at low energies, for particles stopped in PD1, and a more curved part for particles punching through the PD1 photodiode and stopped in the CsI crystal. Due to line crossing and its complex structure, this kind of a map cannot be used for identification, however thanks to the presence of many characteristic punch-through points and curvatures, it is very well suited for energy calibration purposes.

Fig. 7 shows a $\Delta E–E$ map for scintillation signals detected by a second vs third photodiode. Apart from the very good isotopic resolution, one can see a substantial background from the secondary reactions/scatterings in the crystals and also from particles crossing the module at an angle and not originating from the target, as well as back-bendings corresponding to particles punching through the thick crystal (see discussion at the end of this section). Thanks to the pulse shape decomposition, the ionization component for particles hitting the photodiode (nuclear counter effect) at the back of the thick crystal has been easily removed.

Using the individual reconstructed amplitudes for the ionization and for the scintillation components, the map of Fig. 6 can be decomposed into the PD0-PD1(Si) and PD0-PD1(CsI) components of the SCT segment (Figs. 9 and 8). This makes effectively KRATTA even a four-fold telescope.
The isotopic resolution visible from Fig. 8 can be improved by summing up the reconstructed ionization components from PD0 and PD1, and thus, increasing the effective thickness of the first ΔE layer to 1 mm of Si. See also inset in Fig. 14.

Fig. 6. ΔE–E ID map for the first two photodiodes, PD0 vs PD1 (SCT), for particles stopped in PD1 or in the thin crystal (CsI1).

Fig. 7. ΔE–E ID map of scintillation signals for CsI1 vs CsI2 detected by PD1 and PD2.

Fig. 8. Decomposition of the map from Fig. 6. PD0 vs scintillation detected by PD1 – for particles punching through PD1 and stopped in CsI1.

The isotopic resolution visible from Fig. 8 can be improved by summing up the reconstructed ionization components from PD0 and PD1, and thus, increasing the effective thickness of the first ΔE layer to 1 mm of Si. See also inset in Fig. 14. Fig. 11 presents a classical ΔE–E ID map obtained from Fig. 6 thanks to the pulse shape decomposition (see discussion of Fig. 17 for more details on this transformation and Fig. 14 for the corresponding mass resolution.)

Fig. 9. Decomposition of the map from Fig. 6. PD0 vs ionization signal from PD1 – for particles stopped in PD1 (producing no light).

Fig. 10. Fast vs slow components of the scintillation in CsI1. The inset shows more clearly a γ-line and the p, d, t lines.

Fig. 11. Summed PD0 + PD1 ionization components vs scintillation in PD1 for particles stopped in CsI1. Note a slightly improved resolution compared to Fig. 8 (see inset in Fig. 14).

Figs. 10 and 12 show the “Fast–Slow” ID maps for the CsI1 and CsI2 crystals, respectively. The latter represents a variant of the standard representation, using the total light vs the ratio Slow over Fast (see e.g. [36]). The Fast–Slow representation is very useful in many respects in addition to the standard ΔE–E one: One can observe a clear double α line (α–α in Figs. 10 and 12)
which is hidden in the $\Delta E - E$ representation behind the Li isotope lines. The Fast–Slow map shows a clear “$\gamma$-line” – a strong line below the proton line due to $\gamma$-rays (see inset in Fig. 10), which can be precisely isolated and removed from the $\Delta E - E$ map. Last, but not least, as can be seen from Fig. 12, the punch through segments do not cross the lower lying isotope lines in a way they do in case of the $\Delta E - E$ maps (Fig. 7). Thus, the Fast-Slow maps allow to isolate the punch through segments in a much more precise way. Unfortunately, the punch through segments eventually merge with the $\gamma$-lines, which makes it difficult to discriminate between these two.

Fig. 13 demonstrates yet another powerful feature of the pulse shape analysis. It allowed to perform an identification of the majority of light particles stopped in the first photodiode by plotting the amplitude vs mode of the reconstructed current signal (6). Due to the constant value of the field within the intrinsic region of the PIN diode the enhancement of the resolution for stopped particles is not expected to be as pronounced as in the case of reverse mount PN detectors [37], nevertheless, the relation between the range and the carrier collection time seems to be still strong enough to enable the isotopic separation of light particles. This method allowed to reduce the lower identification threshold, due to the thickness of the first photodiode (see Table 2) from 8.3 to about 2.5 MeV for protons, where they are still resolvable from deuterons (see two bottom lines in Fig. 13). This effectively corresponds to the reduction of the thickness of the first $\Delta E$ layer from 500 to about 65 $\mu$m of Si.

One should stress that the time scale presented in Fig. 13 exceeds by about a factor of 3 the collection times estimated on the basis of the mobilities of the carriers alone, thus the plasma delay, or other effects, seem to be quite important in slowing down the collection process.

The mass resolution for particles stopped in the thin crystal (CsI1) and in the thick one (CsI2) can be viewed from Figs. 14 and 15, respectively.

The background in Fig. 14, resulting mainly from the secondary reactions/scattering in the crystal, amounts to about 6% for the hits below the p, d, t peaks. For energetic $Z=1$ particles traversing the thick crystal (12.5 cm of CsI) the secondary reaction probability amounts to about 46% (Fig. 15). These probabilities agree reasonably well with the simple estimates obtained using the nuclear collision length of 22.30 cm for CsI [38], which yields the probabilities of 11% and 43% for 2.5 and 12.5 cm of CsI, respectively. The background measured under the p, d, t lines includes also some contribution from the secondary reactions of neutrons and heavier charged particles, as well as from the accidental coincidences. The $\gamma$ and punch-through hits have been removed from the background, in both cases. The high secondary interaction probability obviously deteriorates the identification quality and defines the limits for applying the telescope method to intermediate energies.

7. Discussion and remarks

Since the parametrization of the pulse shapes is only approximate and has no deep physical background, one can ask how precise is the decomposition into individual components and how physical they are. In order to address these questions, the $\Delta E - E$ map of the SCT (PD1 + CsI1) has been compared to the predictions of the ATIMA range-energy tables. Such a comparison requires the knowledge of the energy calibration of both, the silicon photodiodes and of the CsI(Tl) light output. The calibration has been performed using the ID map of Fig. 6 (see Fig. 16) which is relatively insensitive to the details of the decomposition and is perfectly suited for the energy calibration due to its richness in characteristic punch-through points and curvatures.

The calibration routine allowed to adjust the thicknesses of the dead and active layers, the energy calibration parameters, as well as the light-energy conversion parameters. For the latter, a simple integrated Birks’ formula (see e.g. [34]) has been used, with $dE/dx \propto AZ^2/E$, yielding a commonly applied two-parameter Light-Energy relation [39], applicable for particles stopped in...
The slight overestimation of the free and search for the minimum of the parametrization. In order to obtain this kind of agreement, which can lead, depending also on the starting values, to some local minima, produce discontinuities or lead in directions diverging from the ATIMA lines. The presented agreement has been obtained after searching for the optimal values and fixing some of the parameters (see Table 3). The agreement with the ATIMA lines could be made even better, for instance by freeing the \( \tau_{BE} \) parameter, however at the expense of loosing completely the mass resolution in Fast–Slow representation (contrary to the case presented in Fig. 10). Thus, the presented agreement is a result of an iterative procedure of fixing some of the parameters and also of the energy calibration parameters, but once the crucial parameters are constrained the fitting proceeds automatically.

The whole procedure could probably be better automatized by using more realistic pulse shape parametrizations, especially for individual electron and hole components of the ionization signal, taking into account the plasma delay effects, interactions between carriers, diffusion effects, etc. However, to our knowledge, such pulse shape parametrizations are still to be developed. Definitely, a more realistic preamplifier response function would improve the resolution and would allow for disentangling between physical and instrumental parameters. A more realistic parametrization and analysis would be worth the effort of implementing it to e.g. better understand the relation between the range and the charge collection times which enable the identification of the particles stopped in the silicon detectors. Nevertheless, any more sophisticated analysis would definitely slow down even more the analysis.

Finally, Fig. 18 shows the calculated ATIMA lines superimposed on the \( \Delta E – E \) identification map for scintillation signals from thin vs thick CsI(Tl) crystals. The slight overestimation of the \( \Delta E \) component for \( Z = 1 \) particles results most probably from the simplicity of the Light-Energy conversion formula (7) and (or) from the light output non-uniformity of the crystals. The overall agreement is, nevertheless, quite satisfactory and the calculated lines can be used not only to derive the energy calibration parameters, but also for identification (see Fig. 15), after small manual adjustments.

The energy calibration routine based on the ATIMA range-energy tables operated on all three maps (Figs. 16–18) simultaneously, allowing for a consistent determination of the calibration parameters for all photodiodes and both crystals. Specifically, for the CsI(Tl) crystals with 1500 ppm of Tl concentration, the quenching parameter \( a_2 \) was found to be equal to 0.32, a value compatible with the one from [39] and about 20% larger than the average one quoted for the INDRA crystals [40]. The calibration of the SCT allowed also to estimate the efficiency of the scintillation. The combination of a relatively high Tl doping, high reflectance of the SCT allowed also to estimate the efficiency of the scintillation. This fact is worth noting, since for the “good scintillators” quoted in Ref. [34] this factor amounts to 15–20.

Obviously, a drawback of the telescope method at high energies, is the high level of the secondary reactions. In order to
handle this problem, a more sophisticated methods, neural networks and discriminant analysis are being tested, but this goes beyond the scope of this article.

8. Summary

A new, low threshold, broad energy range, versatile array of triple telescopes, KRAFTA, has been constructed. The modules, equipped with digital electronics chains, allowed for isotopic identification of light charged reaction products.

Pulse shape analysis allowed for realistic decomposition of the complex SCT pulse shapes into individual ionization and scintillation components and eventually profit from the, otherwise harmful, nuclear counter effect. The isotopic resolution obtained using a single readout channel was found to compete very well with those obtained using the standard two channel readout. The applied pulse shape analysis permitted also the identification of particles stopped in the first photodiode and the reduction of the identification threshold, due to the thickness of the first photodiode, by a factor of three. Thanks to the pulse shape analysis, it was also possible to obtain the ballistic deficit free amplitudes, which allowed for easy energy calibration and identification based on the predictions of the range-energy tables.

The array has met the expectations, fulfilled the design requirements and performed very well during the ASY-EOS experiment at GSI.

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